

PS11034**INTEGRATED FUNCTIONS AND FEATURES**

- Converter bridge for 3 phase AC-to-DC power conversion.
- 3 phase IGBT inverter bridge configured by the latest 3rd. generation IGBT and diode technology.
- Inverter output current capability I_o (Note 1):

Type Name	Motor Rating	I_o (100%)	I_o (150%; 60sec)
PS11034	0.75 kW/200V AC	5.0Arms	7.5Arms

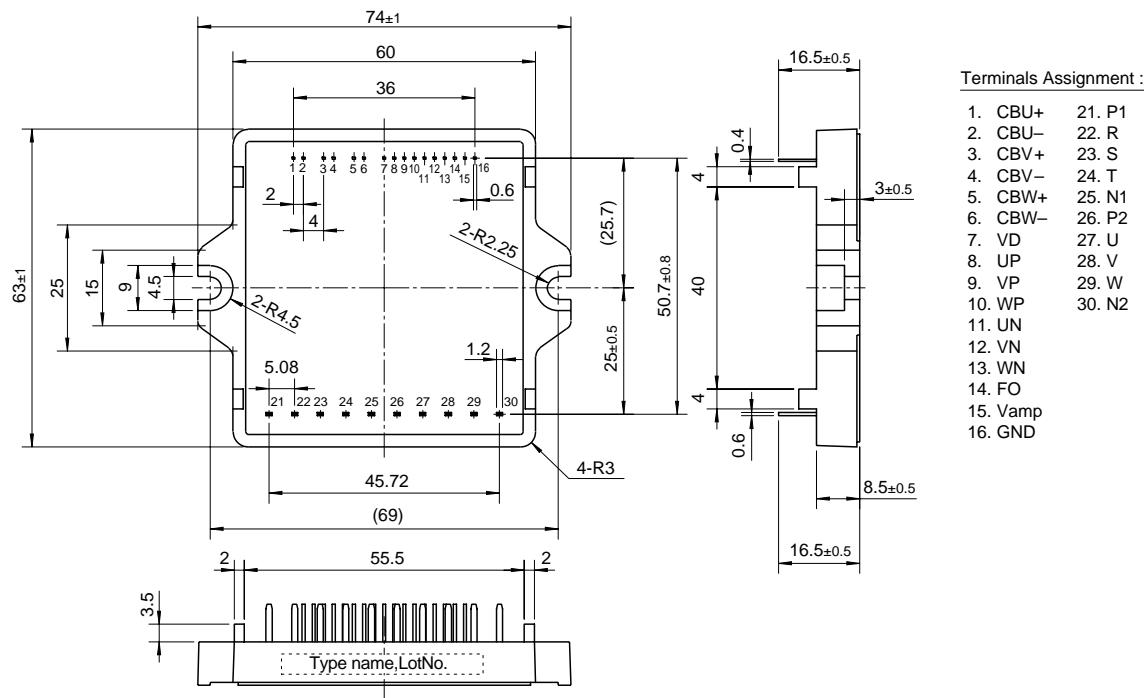
(Note 1) : The inverter output current is assumed to be sinusoidal and the peak current value of each of the above loading cases is defined as : $I_{OP} = I_o \times \sqrt{2}$, $T_C < 100^\circ C$

INTEGRATED DRIVE, PROTECTION AND SYSTEM CONTROL FUNCTIONS:

- P-Side IGBTs : Drive circuit, high-level-shift circuit, bootstrap circuit supply scheme for Single Control-Power-Source drive, and under voltage (UV) protection.
- N-Side IGBTs : Drive circuit, DC-Link current sense and amplifier circuits for overcurrent protection, control-supply under-voltage protection (UV), and fault output (FO) signaling circuit.
- Fault Output : N-side IGBT short circuit (SC), over-current (OC), and control supply under-voltage (UV).
- Inverter Analog Current Sense : N-Side IGBT DC-Link Current Sense.
- Input Interface : 5V CMOS/TTL compatible, Schmitt Trigger input, and Arm-Shoot-Through interlock protective function.

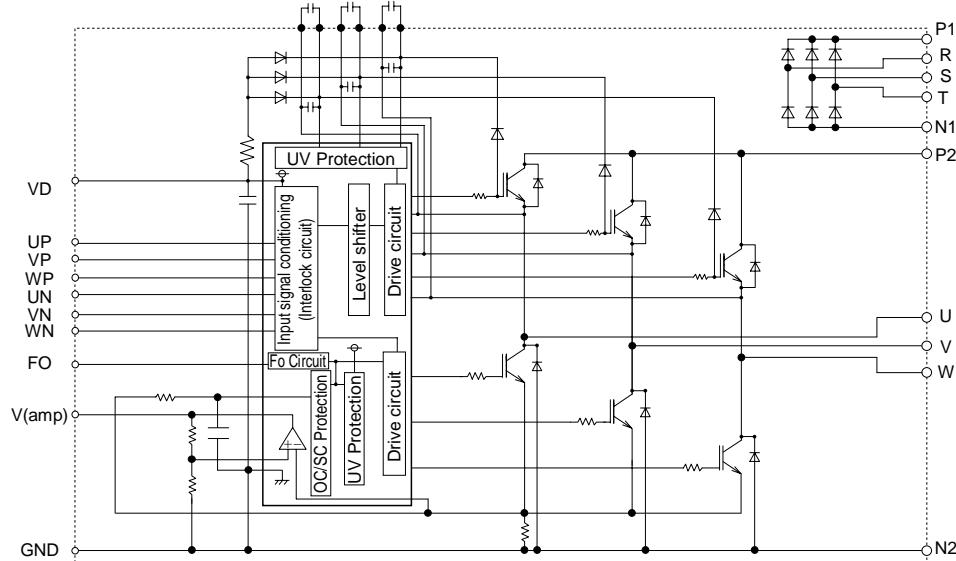
APPLICATION

Acoustic noise-less 0.75kW/200V AC Class 3 phase inverters, motor control applications, and motors with built-in small size inverter package

PACKAGE OUTLINES

(Fig. 1)

INTERNAL FUNCTIONS BLOCK DIAGRAM



(Fig. 2)

MAXIMUM RATINGS ($T_j = 25^\circ\text{C}$)

INVERTER PART

Symbol	Item	Condition	Ratings	Unit
Vcc	Supply voltage	Applied between P2-N2	450	V
VCC(surge)	Supply voltage (surge)	Applied between P2-N2, Surge-value	500	V
VP or VN	Each output IGBT collector-emitter static voltage	Applied between P2-U.V.W, U.V.W-N2	600	V
VP(S) or VN(S)	Each output IGBT collector-emitter switching voltage	Applied between P2-U.V.W, U.V.W-N2	600	V
$\pm I_c(\pm I_{cp})$	Each output IGBT collector current	$T_c = 25^\circ\text{C}$, "()" means I_c peak value	$\pm 15 (\pm 30)$	A

CONVERTER PART

Symbol	Item	Condition	Ratings	Unit
VRRM	Repetitive peak reverse voltage		800	V
Ea	Recommended AC input voltage		220	Vrms
Io	DC output current	3 ϕ rectifying circuit	15	A
IFSM	Surge (non-repetitive) forward current	1 cycle at 60Hz, peak value non-repetitive	150	A
I^2t	I^2t for fusing	Value for one cycle of surge current	93	A ² s

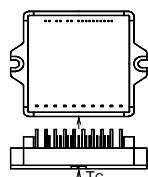
CONTROL PART

Symbol	Item	Ratings	Unit
Vd, Vdb	Supply voltage	-0.5 ~ 20	V
Vcin	Input signal voltage	-0.5 ~ +7.5	V
Vfo	Fault output supply voltage	-0.5 ~ +7.5	V
ifo	Fault output current	15	mA
lamp	DC-Link IGBT current signal Amp output current	1	mA

TOTAL SYSTEM

Symbol	Item	Condition	Ratings	Unit
T _j	Junction temperature	(Note 2)	-20 ~ +125	°C
T _{stg}	Storage temperature	—	-40 ~ +125	°C
T _c	Module case operating temperature	(Fig. 3)	-20 ~ +100	°C
V _{iso}	Isolation voltage	60 Hz sinusoidal AC applied between all terminals and the base plate for 1 minute.	2500	Vrms
—	Mounting torque	Mounting screw: M4	0.98 ~ 1.47	N·m

(Note 2) : The indicated values are specified considering the safe operation of all the parts within the ASIPM. The max. ratings for the ASIPM power chips (IGBT & FWDi) is T_j < 150.

CASE TEMPERATURE MEASUREMENT POINT

(Fig. 3)

THERMAL RESISTANCE

Symbol	Item	Condition	Ratings			Unit
			Min.	Typ.	Max.	
R _{th(jc)Q}	Junction to case Thermal Resistance	Inverter IGBT (1/6)	—	—	2.8	°C/W
R _{th(jc)F}		Inverter FWDi (1/6)	—	—	3.9	°C/W
R _{th(jc)FR}		Converter Di (1/6)	—	—	4.8	°C/W
R _{th(cf)}	Contact Thermal Resistance	Case to fin thermal, grease applied (1 Module)	—	—	0.074	°C/W

ELECTRICAL CHARACTERISTICS (T_j = 25°C, V_d = 15V, V_{db} = 15V unless otherwise noted)

Symbol	Item	Condition	Ratings			Unit
			Min.	Typ.	Max.	
V _{ce(sat)}	Collector-emitter saturation voltage	T _j = 25°C, Input = ON, I _c = 15A, V _d = V _{db} = 15V (Shunt voltage drop not included)	—	—	2.9	V
V _{ec}	FWDi forward voltage	T _j = 25°C, -I _c = 15A	—	—	2.9	V
V _{fr}	Converter diode voltage	T _j = 25°C, I _{fr} = 10A	—	—	1.5	V
I _{rrm}	Converter diode reverse current	V _r = V _{rrm} , T _j = 125°C	—	—	8	mA
t _{on}	Switching times	1/2 Bridge inductive, Input = 5V ↔ 0V V _{cc} = 300V, I _c = 15A, T _j = 125°C V _d = 15V, V _{db} = 15V Note: ton, toff include delay time of the internal control circuit.	0.3	0.6	1.5	μs
t _{c(on)}			—	0.5	1.0	μs
t _{off}			—	1.6	2.5	μs
t _{c(off)}			—	0.5	1.3	μs
t _{rr}			—	0.12	—	μs
Short circuit endurance (Output, Arm, and Load Short Circuit Modes)		@V _{cc} ≤ 400V, Input = 5V → 0V (One-Shot) -20°C ≤ T _j (start) ≤ 125°C, 13.5V ≤ V _d = V _{db} ≤ 16.5V	• No destruction • Fo output by protection operation			
Switching SOA		@V _{cc} ≤ 400V, Input = 5V ↔ 0V, T _j ≤ 125°C I _c < OC trip level, 13.5V ≤ V _d = V _{db} ≤ 16.5V	• No destruction • No protecting operation • No Fo output			

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$, $V_d = 15\text{V}$, $V_{db} = 15\text{V}$ unless otherwise noted)

Symbol	Item	Condition	Ratings			Unit
			Min.	Typ.	Max.	
I_d	Circuit current (Average)	$T_j = 25^\circ\text{C}$, $V_d = 15\text{V}$, $V_{in} = 5\text{V}$	—	—	50	mA
I_{db}	Circuit current (Average)	$T_j = 25^\circ\text{C}$, $V_d = V_{db} = 15\text{V}$, $V_{in} = 5\text{V}$	—	—	5	mA
$V_{th(on)}$	Input on threshold voltage		0.8	1.4	2.0	V
$V_{th(off)}$	Input off threshold voltage		2.5	3.0	4.0	V
R_i	Input pull-up resistor	Applied between input terminal-inside power supply	—	50	—	k Ω
f_{PWM}	PWM input frequency	$T_c \leq 100^\circ\text{C}$, $T_j \leq 125^\circ\text{C}$	1	—	15	kHz
t_{dead}	Arm shoot-through blocking time	Relates to corresponding inputs $T_c = -20^\circ\text{C} \sim +100^\circ\text{C}$ (Note 3)	2.2	—	—	μs
t_{int}	Input interlock sensing	Relates to corresponding input (Fig. 6)	—	100	—	ns
$V_{amp(100\%)}$	Inverter DC-Link IGBT current sense voltage output signal	$I_c = I_{OP}(100\%)$	$V_d = 15\text{V}$	1.5	2.0	2.5
$V_{amp(200\%)}$		$I_c = I_{OP}(200\%)$	$T_j = 25^\circ\text{C}$ (Fig. 4)	3.0	4.0	5.0
$V_{amp(250\%)}$	Inverter DC-Link IGBT current sense voltage output limit	$I_c = I_{OP}(250\%)$	$V_d = 15\text{V}$	5.0	—	—
$V_{amp(0)}$		$I_c = 0\text{A}$	(Fig. 4)	—	50	100
O_C	Over current trip level	$T_j = 25^\circ\text{C}$	(Fig. 5)	14.2	17.7	25.0
t_{OC}	Over current delay time	$T_j = 25^\circ\text{C}$	(Fig. 5)	—	10	—
S_C	Short circuit trip level	$T_j = 25^\circ\text{C}$	(Fig. 5)	—	30	—
t_{SC}	Short circuit delay time	$T_j = 25^\circ\text{C}$	(Fig. 5)	—	2	—
UV_D	Supply circuit under voltage protection	Trip level	$T_c = T_j = 25^\circ\text{C}$ (Fig. 5)	11.0	12.0	13.0
UV_{Dr}		Reset level		11.5	12.5	13.5
UV_{DB}		Trip level		10.1	10.8	11.6
UV_{DBr}		Reset level		10.6	11.3	12.1
t_{dV}		Delay time		—	10	—
t_{FO}	Fault output pulse width	$T_j = 25^\circ\text{C}$	(Note 4)	1.0	1.8	—
$I_{FO(H)}$	Fault output current	Open collector output	(Note 4)	—	—	1 μA
$I_{FO(L)}$				—	—	15 mA

(Note 3) : The dead-time has to be set externally by the CPU; it is not part of the ASIPM internal functions.

(Note 4) : Fault output signaling is given only when the internal OC, SC, & UV protection circuits are activated.

The OC, SC and UV protection (and fault output) operate for the lower arms only. The OC and SC protection Fault output is given in a pulse format while that of UV protection is maintained throughout the duration of the under-voltage condition.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Condition	Ratings			Unit
			Min.	Typ.	Max.	
V_{CC}	Supply voltage	Applied across P2-N2 terminals	—	300	400	V
V_d	Supply voltage	Applied between V_d -GND	13.5	15.0	16.5	V
V_{db}	Supply voltage	Applied between CBU+ & CBU-, CBV+ & CBV-, CBW+ & CBW-	13.5	15.0	16.5	V
$\Delta V_d, V_{db}$	Supply voltage ripple		-1	—	+1	V/ μs
$V_{CIN(ON)}$	Input on voltage	Applied between UP • VP • WP • UN • VN • WN and GND	0	—	0.8	V
$V_{CIN(OFF)}$	Input off voltage	GND	4.0	—	5.0	V
t_{dead}	Arm shoot-through blocking time	Relates to corresponding inputs	2.2	—	—	μs
T_c	Module case operating temperature		—	—	100	°C
f_{PWM}	PWM Input frequency	$T_c \leq 100^\circ\text{C}$, $T_j \leq 125^\circ\text{C}$	—	—	15	kHz
t_{xx}	Allowable minimum input on-pulse width		1	—	—	μs

INVERTER DC-LINK IGBT CURRENT ANALOGUE SIGNALING OUTPUT (TYPICAL)

